

# DMTH6006LPSWQ

### 60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>C</sub> = +25°C (Note 9)
60V	6.5mΩ @ V <sub>GS</sub> = 10V	100A
	10mΩ @ V <sub>GS</sub> = 4.5V	81.6A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

### Features

- Rated to +175°C —Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production— Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub>—Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6006LPSWQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)

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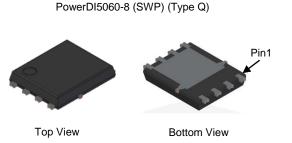
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• Weight: 0.097 grams (Approximate)

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Internal Schematic



# Ordering Information (Note 4)

	Part Number	Case	Packaging		
	DMTH6006LPSWQ-13	PowerDI5060-8 (SWP) (Type Q)	2500/Tape & Reel		
Notes:	Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.				

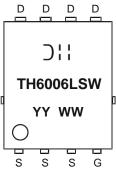
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

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3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



D11 = Manufacturer's Marking
TH6006LSW = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 19 = 2019)
WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

Document number: DS41360 Rev.2 - 2

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Top View

**Pin Configuration** 



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	60	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, $V_{GS}$ = 10V (Note 5)	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	17.2 12.1	А
Continuous Drain Current, $V_{GS}$ = 10V (Notes 6 & 9)	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	100 71.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	400	А	
Maximum Continuous Body Diode Forward Current (Note	Is	100	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cy	I <sub>SM</sub>	400	А	
Avalanche Current, L=0.1mH		I <sub>AS</sub>	28.5	А
Avalanche Energy, L=0.1mH		E <sub>AS</sub>	40.7	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.88	W
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>ƏJA</sub>	52	°C/W
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	PD	100	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>eJC</sub>	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	- <b>,</b>		- 76				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)		-			-		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.2	—	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	4.9	6.5	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	7.1	10	11122	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A	
Diode Forward Voltage	V <sub>SD</sub>		0.8	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)	•						
Input Capacitance	Ciss	_	2162	—		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	761	—	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>		58	—			
Gate Resistance	Rg	-	0.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	18.1	—		V <sub>DS</sub> = 30V, I <sub>D</sub> = 20A	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	34.9	—	nC		
Gate-Source Charge	Q <sub>gs</sub>	—	6.1	—	nc		
Gate-Drain Charge	Q <sub>gd</sub>	_	7.3	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.0	—		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 20A, R_g = 3\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	5.4	—	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	20.4	—	115		
Turn-Off Fall Time	tF		7.8	—		-	
Body Diode Reverse Recovery Time	t <sub>RR</sub>	-	35.8	—	ns	1 - 200 di/dt - 1000/uc	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		40.2	—	nC	I <sub>F</sub> = 20A, di/dt = 100A/μs	

5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

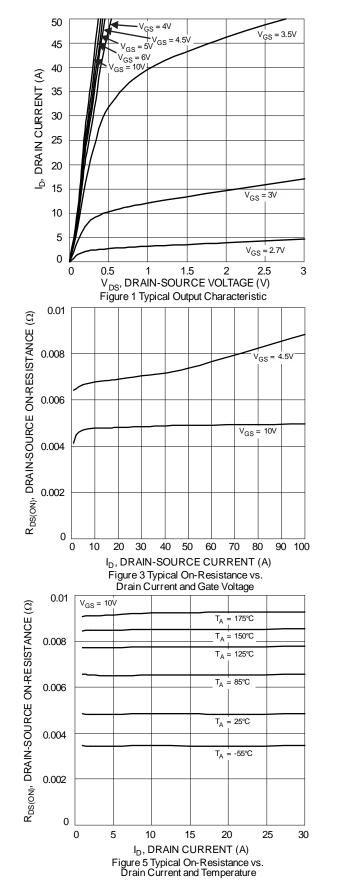
6. Thermal resistance from junction to soldering point (on the exposed drain pad).

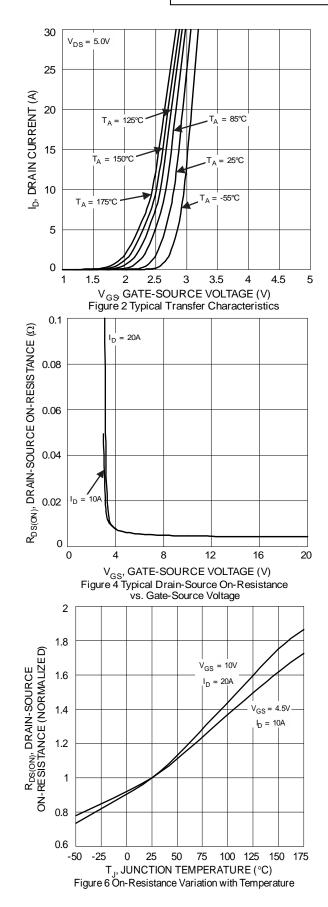
7. Short duration pulse test used to minimize self-heating effect.

B. Guaranteed by design. Not subject to product testing.
 Limited by package.



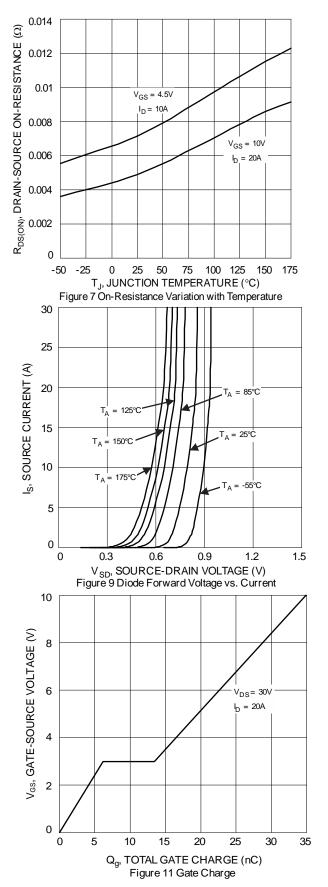
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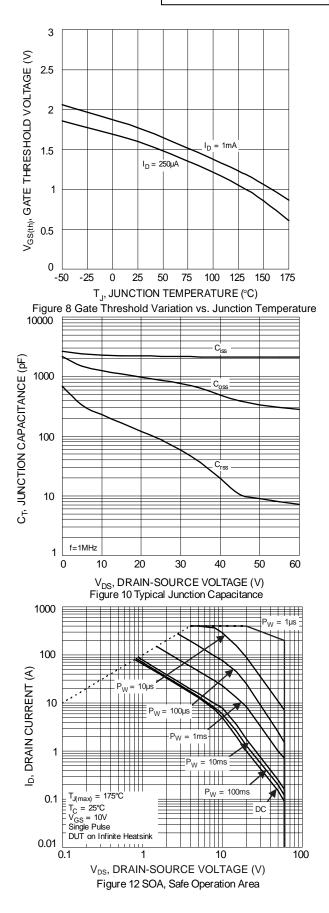






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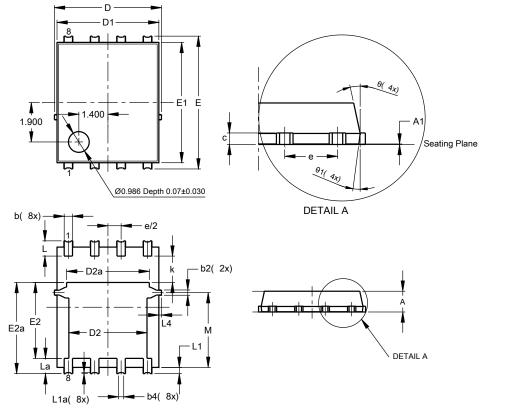






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



### PowerDI5060-8 (SWP) (Type Q)

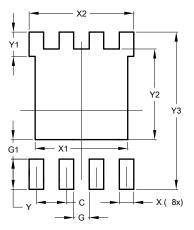
(Type Q)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	(	).25REF	-		
С	0.230	0.330	0.277		
D	5	.15 BS0	0		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6	.40 BS0	0		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC	)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0	.050RE	F		
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

PowerDI5060-8 (SWP)

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8 (SWP) (Type Q)



Dimensions	Value		
Dimensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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